





What is Optoelectronics?



- A field of technology that combines the physics of light with electricity. Optoelectronics encompasses the study, design and manufacture of hardware devices that convert electrical signals into photon signals and vice versa.
- Any device that operates as an electrical-to-optical or optical-to-electrical transducer is considered an optoelectronic device.
- Optoelectronic technologies include fiber optic communications, laser systems, electric eyes, and are widely used in the daily household appliances, office electronics, lighting, remote sensing systems, medical diagnostic systems and optical information systems.



Different point of views

- Optoelectronics is a branch of electronics that overlaps with physics. The field concerns the theory, design, manufacture, and operation of hardware that converts electrical signals to visible or infrared radiation (infrared) energy, or vice-versa.
- Optoelectronics is the branch of physics that studies the mutual conversion of electricity and light energy.



Optoelectronics (contents)

- Laser theory and techniques
- Semiconductor light device
- Photodetectors
- Modulation (electro-optics effect, Photoacoustic effect, Magnetoptics effect)
- Display
- Nonlinear optics



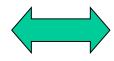
Including

- Optoelectronic components for example: photocells, solar cells, detector arrays, opto-isolators (also called optical couplers or optocouplers), modulator, LEDs (light-emitting diodes), laser, and laser diodes.
- Applications include light sources, electric eyes, photovoltaic power supplies, various monitoring and control circuits, and optical fiber communications systems, display, information storage.



Optoelectronics





Photons



Different relations between photon and other physical parameters:

laser sources E~Photon

semiconductor E_{Photon}~Eg

Photodetector E_{Photon}>Eg

Electro-optical effect N~E

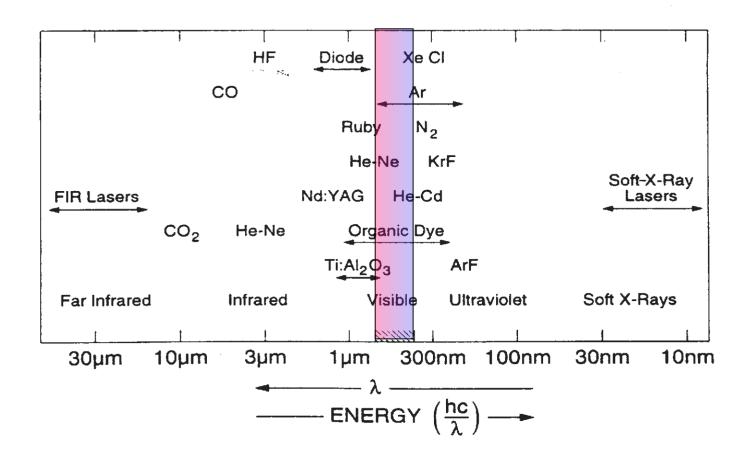
Acoustic optics, N~Phonon,

magnetic optics N~B

non-linear effect N~I³, I²



Luminescent spectrum of different materials



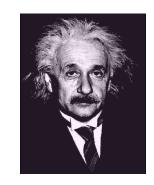


Laser theory is the basic part of Optoelectronics



History of Laser

- LASER <u>Light Amplification by Stimulated Emission of Radiation</u>
- 1917
 - Albert Einstein first theorized about the process which makes lasers possible called "Stimulated Emission"
- 1951
 - Charles H. Townes conceived the concept of MASER (Microwave Amplification by Stimulated Emission of Radiation)
- 1954
 - First MASER device by Townes, Gould and Zerger
- 1958
 - Schawlow and Townes showed theoretically that masers could be made to operate in the optical and infrared region
 - "Infrared and Optical Masers," published in the December 1958 *Physical Review*.
 - Received a patent for the invention of the laser in 1960



Albert Einstein

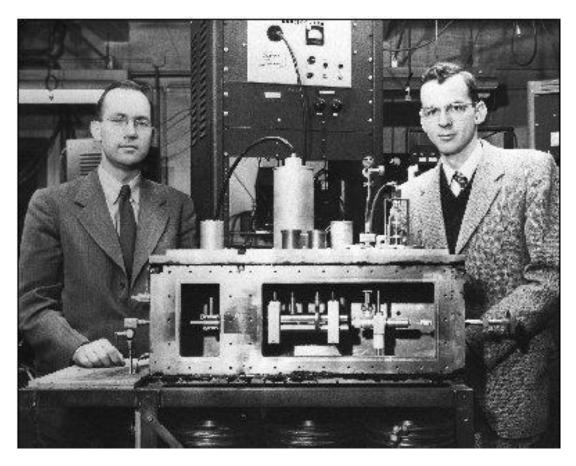


Arthur L. Schawlow



Charles H. Townes





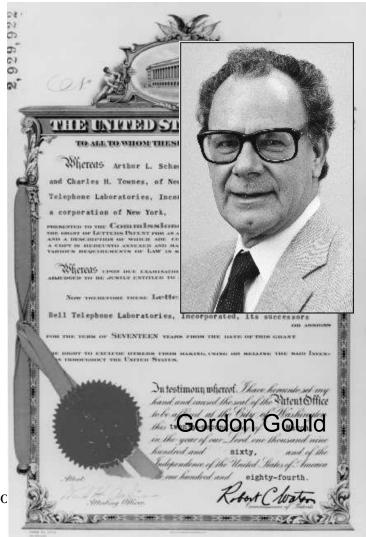
Charles Townes (left) and James P. Gordon proudly display their maser, a device that greatly amplifies microwaves



History of Lasers

Laser Patent War

- Gordon Gould then 37-year-old Columbia graduate student
 wrote down his laser ideas including a definition of "laser" as Light Amplification by the Stimulated Emission of Radiation in late 1957, and had them notarized. Filed for patent in 1959, but was rejected.
- The laser patent was later bitterly disputed for almost three decades in "the patent wars" by Gordon Gould, and his designated agents.
- Gordon Gould eventually received the US patent for optical pumping of the laser in 1977 since the original laser patent did not detail such a pumping procedure. In 1987 he also received a patent for the gas discharge laser, thereby winning his 30 year patent war. His original notebook even contained the word "laser"..

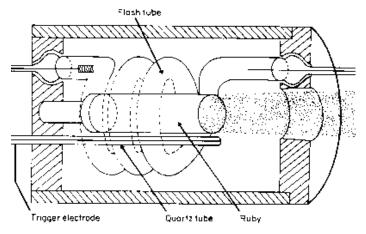




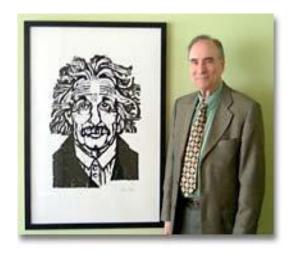
History of Lasers (Cont'd)

• 1960

 Theodore H. Maiman (Hughes Research) made the first working laser
 Ruby laser @ 0.69 μm



The first Ruby laser in the world



Theodore H. Maiman

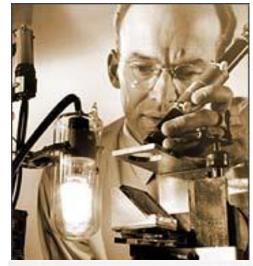


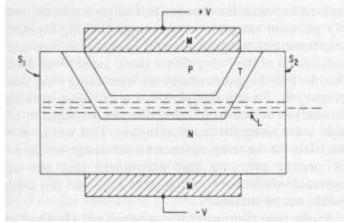
Ali Javan and his associates William Bennett Jr. and Donald Herriott at Bell Labs were first to successfully demonstrate a continuous wave (cw) helium-neon laser operation (1960-1962).(Courtesy of Bell Labs, Lucent Technologies.)





• In 1962 Robert Hall invented the semiconductor injection laser, a device now used in all compact disk players and laser printers, and most optical fiber communications systems.





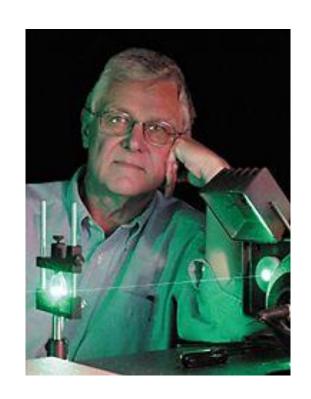




1964: C. K. N. Patel shown here with the high-power 10.6 micron carbon dioxide laser which he developed at Bell Labs.



1964 William Bridges Invention of Argon Ion LASER a Hughes Labs.

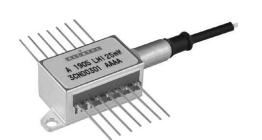




Diode laser



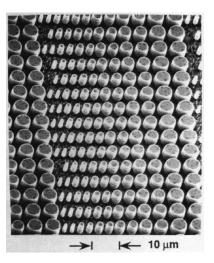
A laser diode pigtailed to a fiber. Two of the leads are for a back-facet photodetector to allow the monitoring of the laser output power.(Courtesy of Alcatel)



A 1550 nm MQW-DFB InGaAsP laser diode pigtail-coupled to a fiber



An 850 nm VCSEL diode



SEM (scanning electron microscope) of the first low-threshold VCSELs developed at Bell Laboratories in 1989. The largest device area is 5 µm in diameter 19

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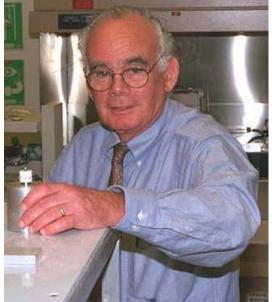
Optoelectronics Introduction



Diode laser

 Coherent light emission from a semiconductor (gallium arsenide) diode (the first *laser* diode) was demonstrated in 1962 by two US groups lead by Robert N. Hall at the General Electric research center and by Marshall Nathan at the IBM T.J. Watson Research Center







- 375 nm excitation of Hoechst stain, Calcium Blue, and other fluorescent dyes in fluorescence microscopy
- 405 nm InGaN blue-violet laser, in Blu-ray Disc and HD DVD drives
- 445 nm InGaN Deep blue laser diode recently introduced (2010) for use in high brightness data projectors
- 473 nm Bright blue laser pointers, still very expensive, output of DPSS systems
- **485 nm** excitation of GFP and other fluorescent dyes
- **510 nm** Green diodes recently (2010) developed by Nichia for laser projectors.
- **532 nm** AlGaAs-pumped bright green laser pointers, frequency doubled 1064 nm Nd:YAG laser or (more commonly in laser pointers) Nd:YVO₄ IR lasers (SHG)
- **593 nm** Yellow-Orange laser pointers, DPSS (Diode Pumped Solid State)
- 635 nm AlGaInP better red laser pointers, same power subjectively 5 times as bright as 670 nm one
- **640 nm** High brightness red DPSS laser pointers
- **657 nm** AlGaInP DVD drives, laser pointers
- **670 nm** AlGaInP cheap red laser pointers
- **760 nm** AlGaInP gas sensing: O₂
- **785 nm** GaAlAs Compact Disc drives
- **808 nm** GaAlAs pumps in DPSS Nd:YAG lasers (e.g. in green laser pointers or as arrays in higher-powered lasers)
- 848 nm laser mice
- 980 nm InGaAs pump for optical amplifiers, for Yb:YAG DPSS lasers
- **1064 nm** AlGaAs fiber-optic communication
- **1310 nm** InGaAsP fiber-optic communication
- **1480 nm** InGaAsP pump for optical amplifiers
- 1512 nm InGaAsP gas sensing: NH₃
- **1550 nm** InGaAsP fiber-optic communication
- **1625 nm** InGaAsP fiber-optic communication, service channel
- **1654 nm** Inga Asp gas sensing: CH₄
- **1877 nm** GaSbAs gas sensing: H₂O
- **2004 nm** GaSbAs gas sensing: CO₂
- 23307mm17 GaSbAs gas sensing: CO Optoelectronics Introduction

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Inventors of different Lasers

- > 1961
 - Ali Javan (Bell Labs) invented the first gas or helium neon laser
- > 1962
 - Robert Hall (GE Research) invented semiconductor lasers
- > 1964
 - J.E. Geusic invented the first working Nd:YAG laser
- > 1966
 - William T. Silfvast invented the first metal vapor laser – blue He-Cd laser
- **>**



The history of laser in China

1961年中国红 宝石激光器 (王之江)





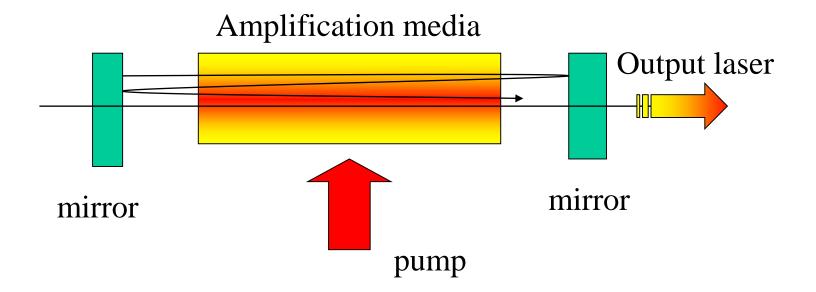


The first different kind of laser in China

Lasers	Invention time	Inventor
He-Ne laser	1963年7月	邓锡铭等
掺钕玻璃 laser	1963年6月	干福熹等
GaAs semiconductor laser	1963年12月	王守武等
Pulse Ar+ laser	1964年10月	万重怡等
CO ₂ laser	1965年9月	王润文等
CH ₃ I chemical laser	1966年3月	邓锡铭等
YAG laser	1966年7月	屈乾华等

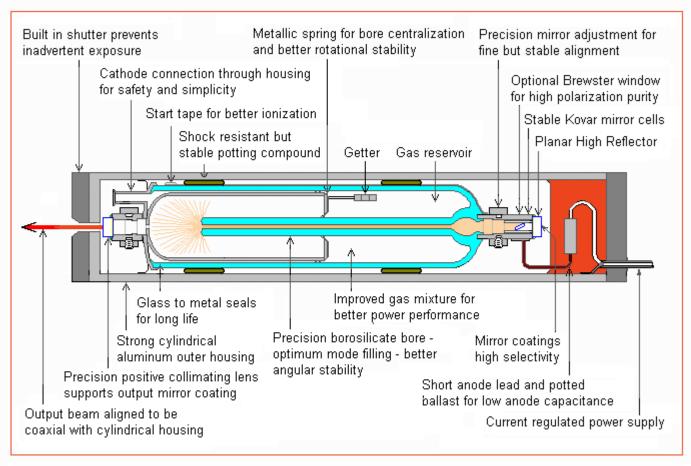


The basic components of laser



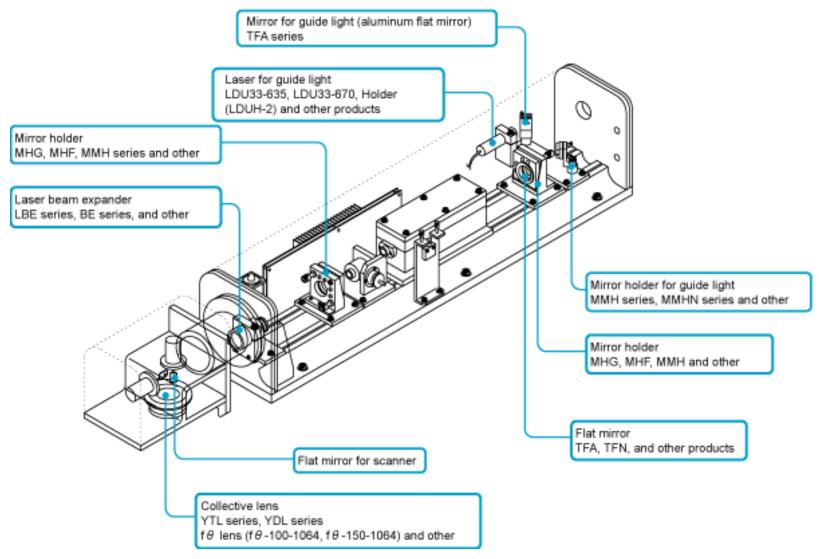


Gas laser (He-Ne)



Cross Sectional View of a Melles Griot HeNe Laser Head Showing Details of the Plasma Tube

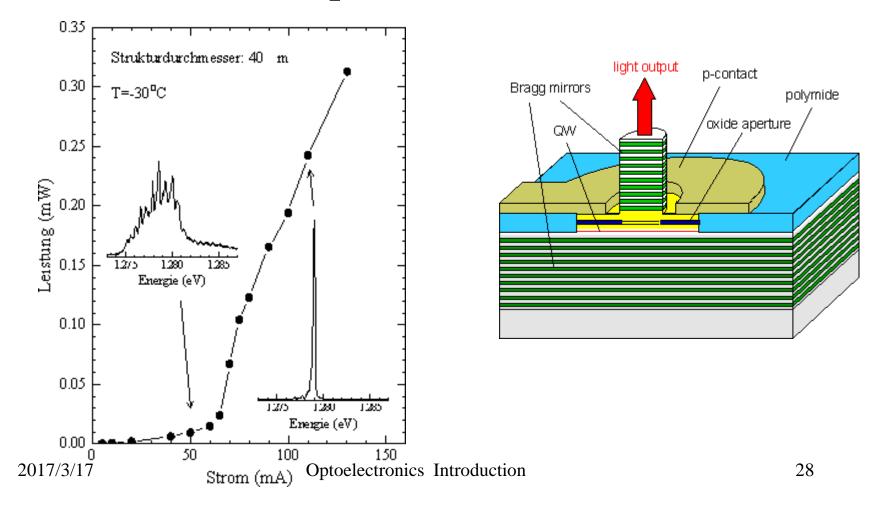






Microcavity Laser Structure

Laser Emission Spectrum





DFB (Distributed Feedback) laser

High output power

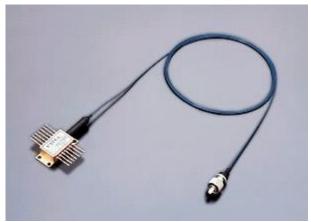
The high output power can compensate for various optical losses within DWDM systems, enabling configuration of multichannel transmission systems and amplifier-less systems.

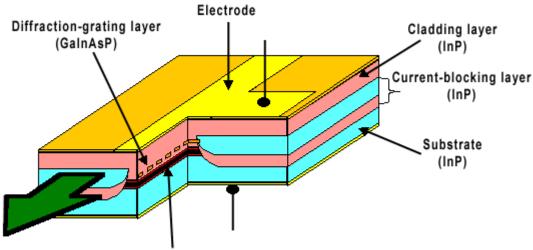
Low power consumption

Because of its low power consumption, the laser can substantially suppress wavelength fluctuation --an important parameter for signal light sources for DWDM systems, resulting in improvements of product reliability.

Wavelength stability

A DFB laser module is incorporating a wavelength stabilizing function The module can suppress wavelength fluctuations within 10 pico-meter.

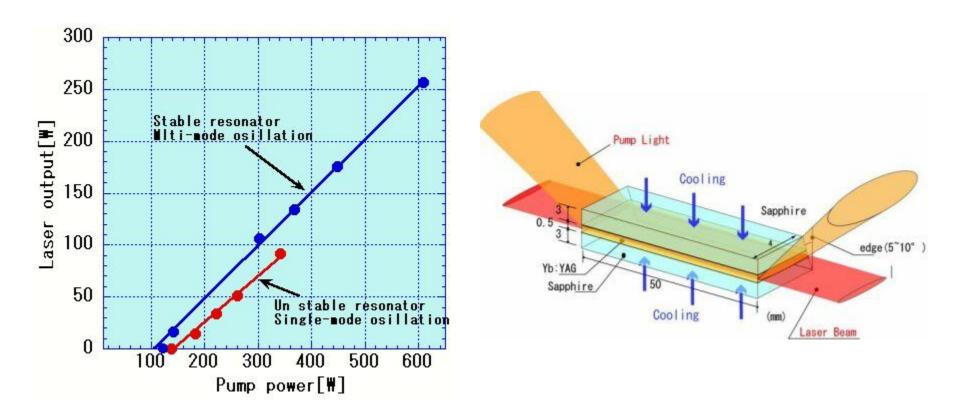




Quantum-well light emitting layer(GalnAsP)



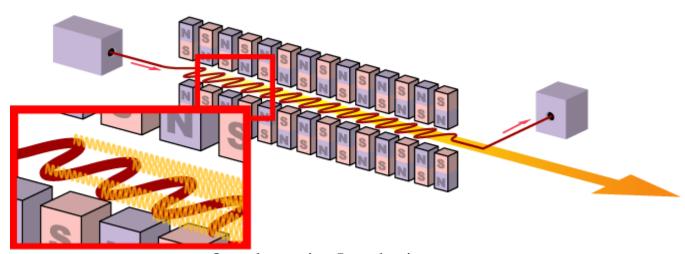
Structure of sub-millimeter-thickness slab





Free-electron laser

• FELs use a relativistic electron beam as the lasing medium which moves freely through a magnetic structure, hence the term *free electron*. The free-electron laser has the widest frequency range of any laser type, and can be widely tunable, currently ranging in wavelength from microwaves, through terahertz radiation and infrared, to the visible spectrum, to ultraviolet, to X-rays





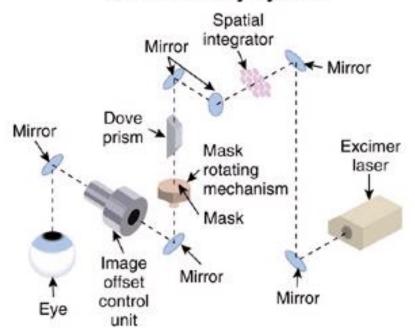
Laser classification

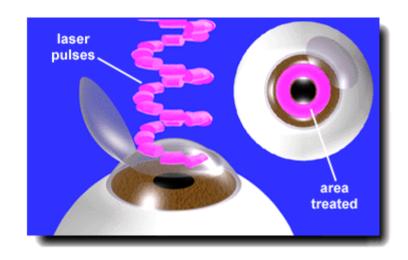
- Gas laser
- Solid state laser
- Semiconductor laser
- Dye laser
- Free electron laser
- Fiber laser
- Photonic crystal laser



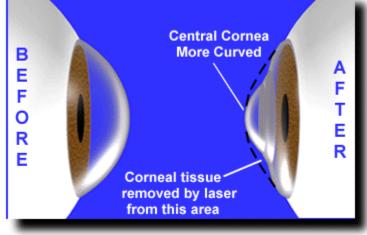
Excemer laser (ultraviolet)

Beam delivery system





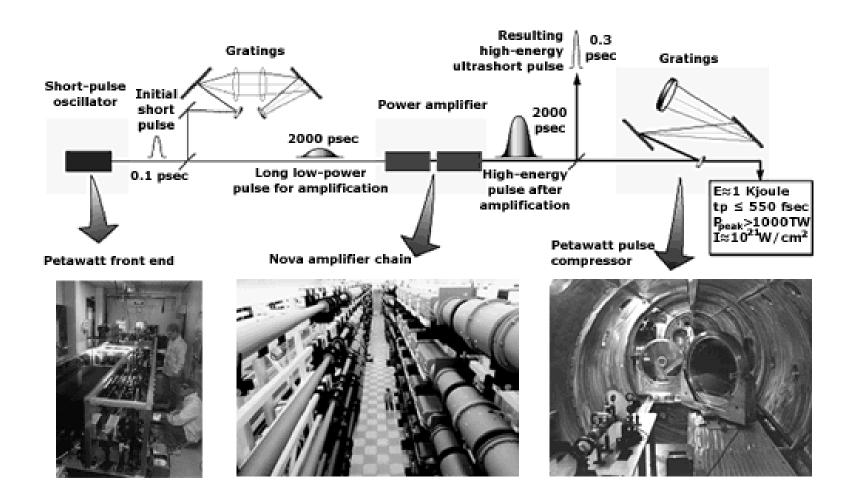




Optoelectronics Introdu

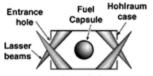


Laser fusion (new energy)

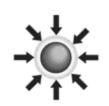




 Schematic of conventional inertial confinement fusion; (bottom row) Schematic of the fast ignitor concept



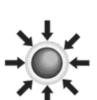
Indirect Drive



Direct Drive



Laser or particle beams rapidly heat the surface of the fusion target forming a surrounding plasma envelope



Atmosphere Formation

Laser or particle beams rapidly heat the surface of the fusion target forming a surrounding



Fuel is compressed by rocket-like blowoff of the surface material

During the final part of the reaches 20 times the

Ignition

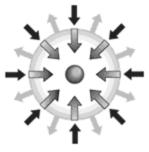
implosion, the fuel core density of lead and ignites at 100,000,000°C.

Burn

Thermonuclear burn spreads rapidly through the compressed fuel, yielding many times the driver input energy

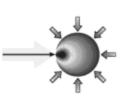


plasma envelope



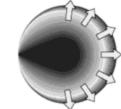
Compression

Fuel is compressed by rocket-like blowoff of the surface material



Ignition

At the moment of maximum compression a short (1-10 psec) high intensity (1019 W/cm2) pulse ignites the capsule



Burn

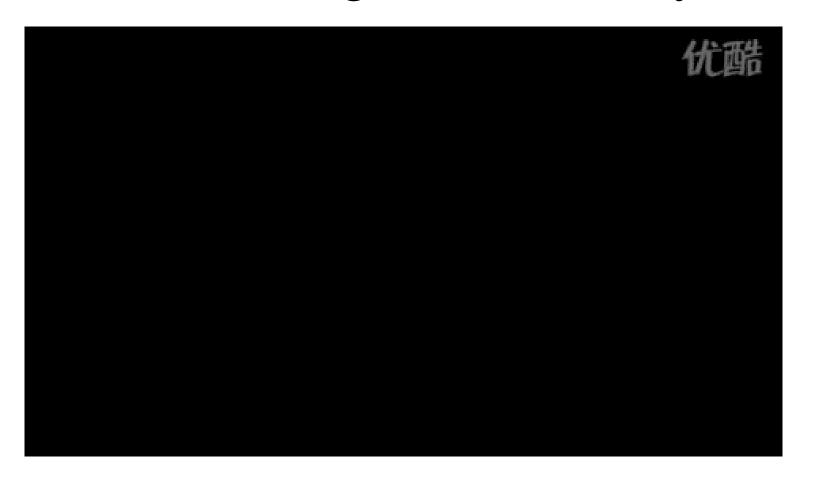
Thermonuclear burn spreads rapidly through the compressed fuel, yielding many times the driver input energy

Laser energy

Inward transported thermal energy



National Ignition Facility





Laser machine

Lasing Materials	Applications
CO ₂	Boring Cutting/Scribing Engraving
Nd	High-energy pulses Low repetition speed (1 kHz) Boring
Nd-YAG	Very high energy pulses Boring Engraving Trimming
Fiber laser	Convenience in the application







Light sources

Incandescent lamp



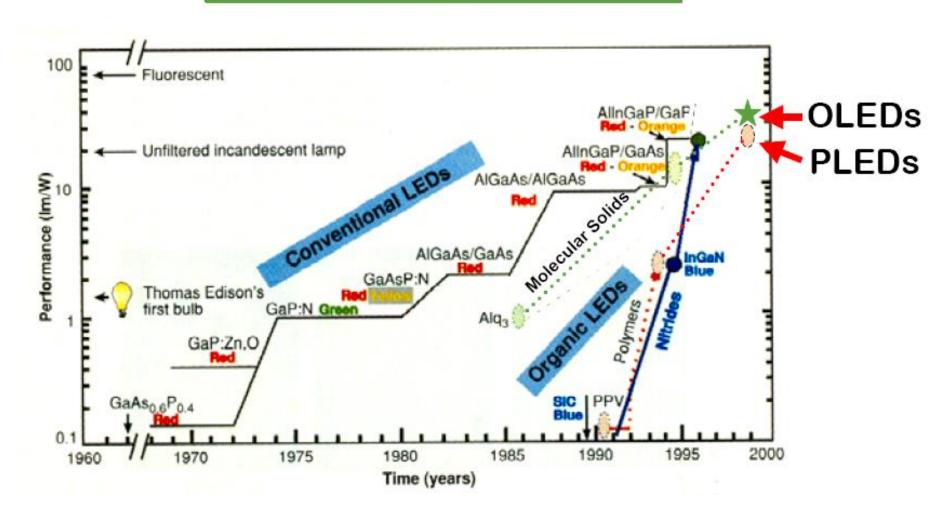
Gas discharge lamp

• Semiconductor light source





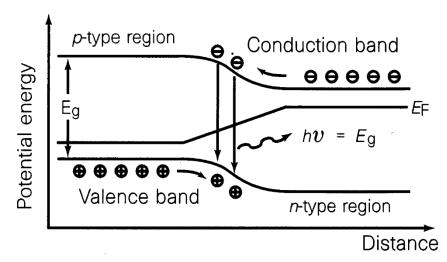
Progress in LED Efficiency

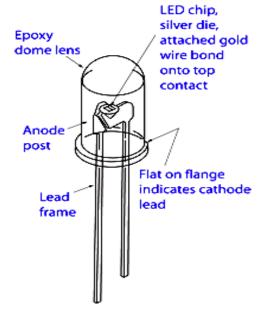


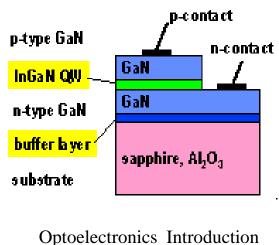


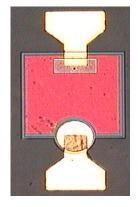
LED (light emitting diode)







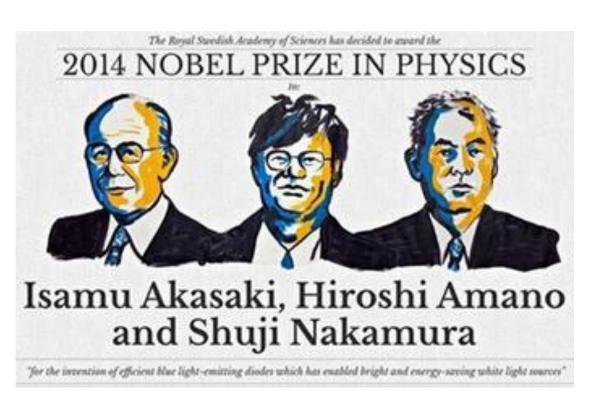








2014 Nobel Price (Physics)



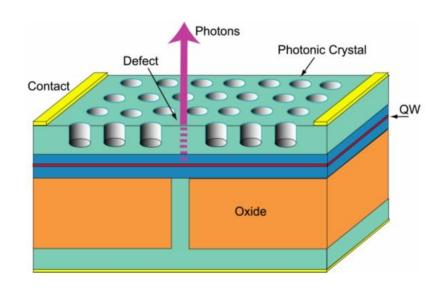




Photonic crystal to increase the efficiency

Quantum efficiency

Out coupling efficiency





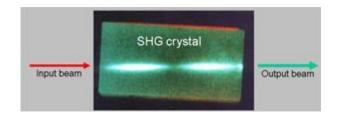
Electro-optical effect (Display)

- Electro-optical modulation technique
 - EO crystal
 - Liquid crystal









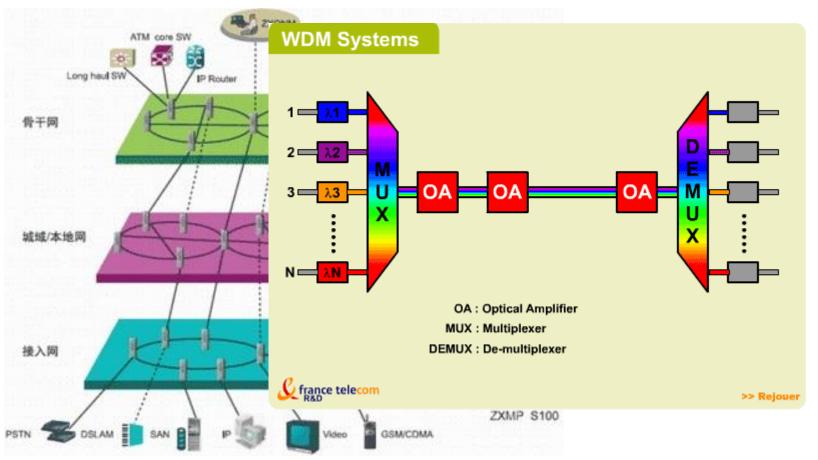


液晶 (Liquid Crystal)



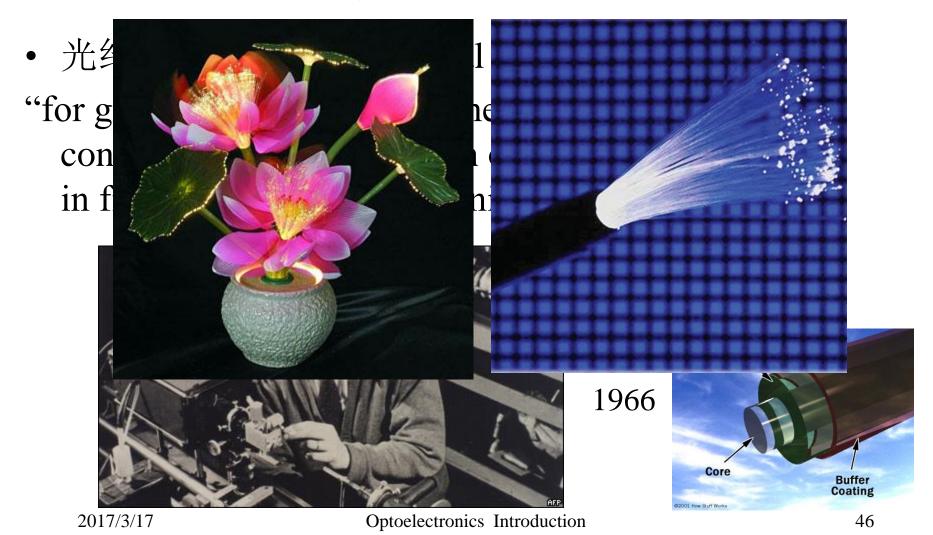


Optical communication (light sources, propagation and detection)





2009年诺贝尔物理奖





Optical Signal to Electric Signal

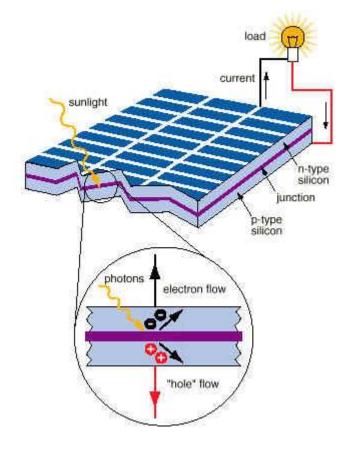
光电转换技术



Photo detector

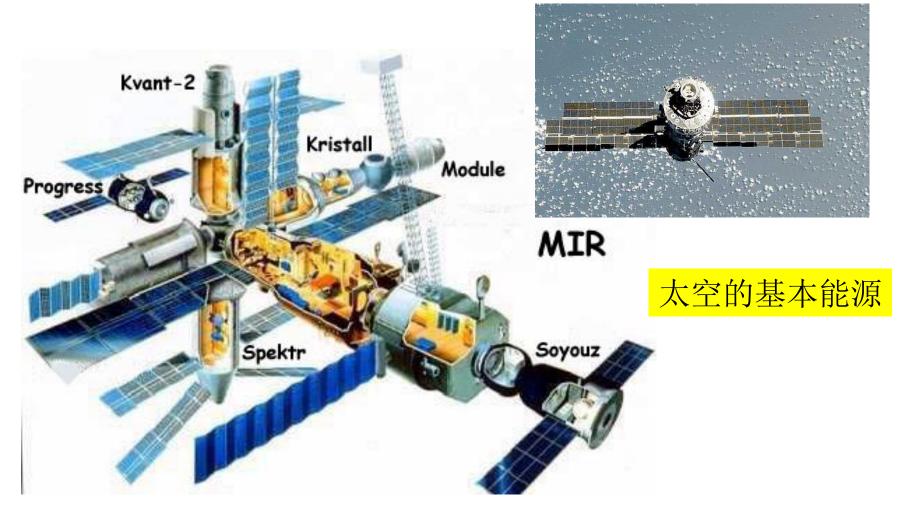
• Photovoltaic effect — Solar cell







Aerospace

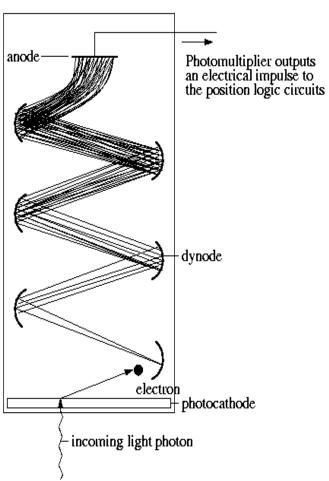




Photodetector (2)

- UV+visible+nIR
- PMT Photomultiplier tube (vacuum + photocathode)





A Photomultiplier Tube

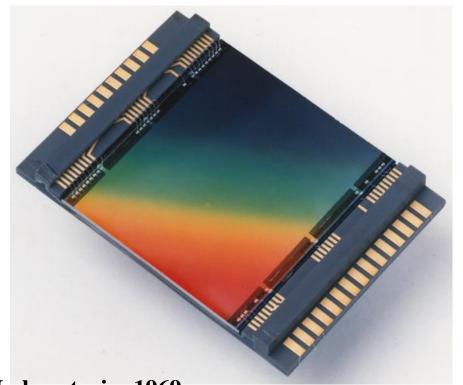


photodetector (2)

• CCD device

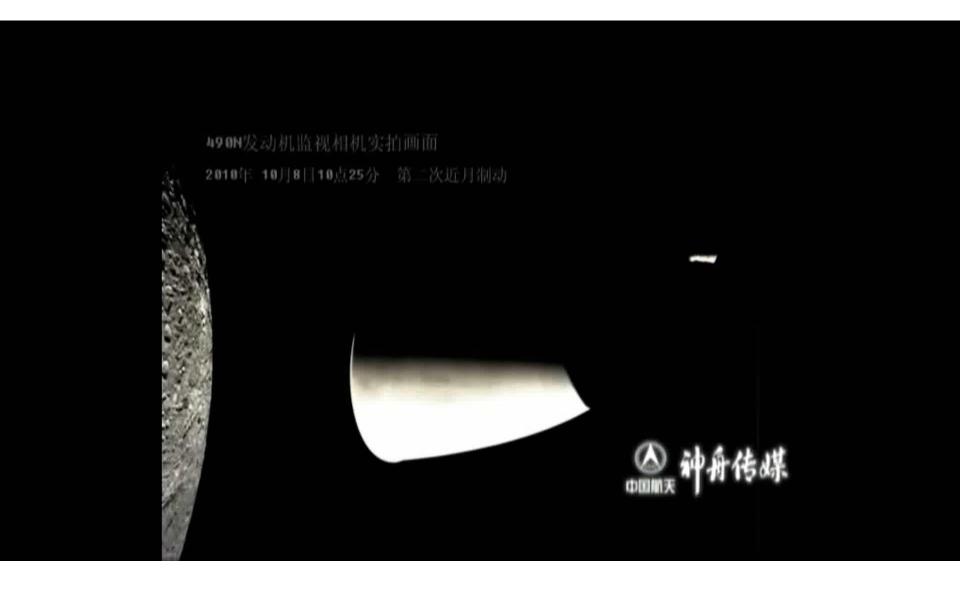






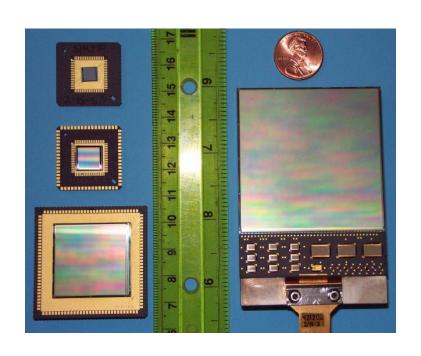
George E. Smith Bell Laboratories 1969 Willard S. Boyle for the invention of an imaging semiconductor circuit – the CCD sensor"

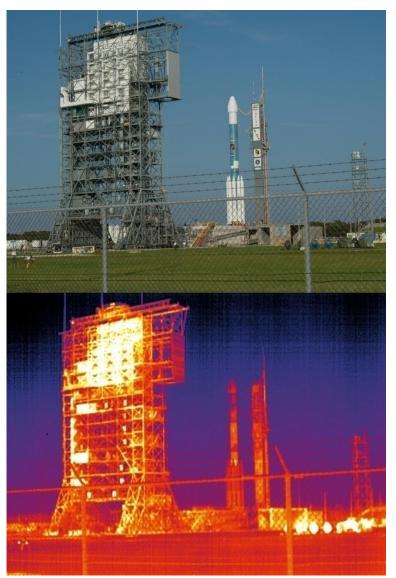






• Infrared array detector







Photodiode & PIN

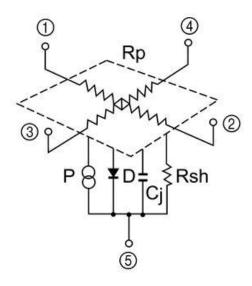
• PIN InGaAs



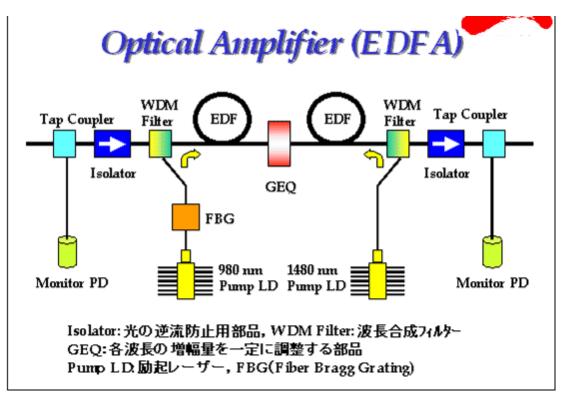
PSD

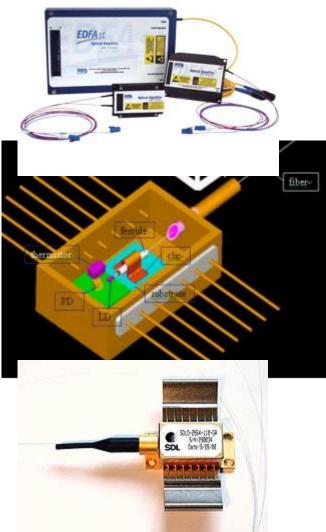
Position Sensitive Device







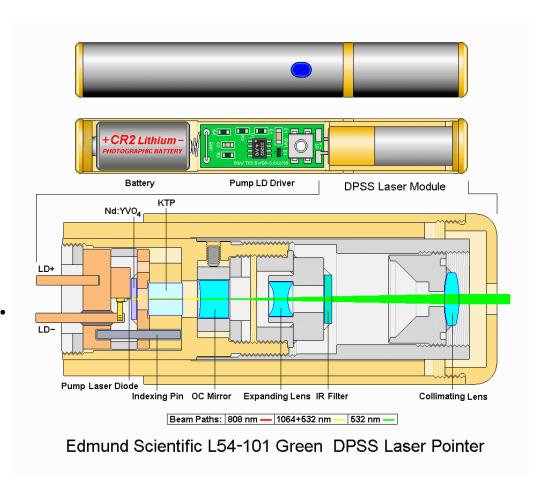






Nonlinear optics and crystal

- Double frequency
- 3rd frequency
- We can almost get all the laser in any wavelength we like.
- Laser pointer





Reference text books

- B. H. Salsh: Fundamental of photonics
- W. Koechner: Solid-State Laser Engineering (Spring Verlag, 1999)
- A.E. Siegman: Lasers (University Science Books, 1986)
- W.T. Silfvast: Laser Fundamentals (Cambridge University Press, 1996)
- 克希耐尔, 固体激光工程, 科学出版社 2002
- 马养武,光电子学,浙江大学出版社,2001
- Self-edit textbook, 光电子学 (ver.2) 2011.2

http://opt.zju.edu.cn/optelec/index.php



The background industries of OEs

- Industry of laser
- Optical communication
- Display industry
- Imaging Industry
- Photo-detectors industry



The schedule of the course

- Times: two short terms, 3hs/week
- Home works: after each course
- Mid term examination: 28th April
- 2 projects

visit:

http://opt.zju.edu.cn/optelec/index.php

• Final exam: End of June.







2018全国大学生光电竞赛

- 竞赛题目1: 穿透毛玻璃的可见光成像系统
- 竞技重点: 在复杂介质成像过程中提取图像信息的能力。
- 竞赛说明: 使用CMOS或者CCD成像系统透过毛玻璃对目标物体成像。
- 竞赛规则:

使用自行设计的CMOS或CCD成像系统,透过毛玻璃对目标物体成像。毛玻璃与目标物之间不可添加任何光学元件和照明光源。目标物体为打印在透明胶片上的5种字号的黑色"E"字符,每种字号的"E"有多个随机朝向。目标物体距离毛玻璃板5cm。



2018全国大学生光电竞赛

- 竞赛题目2: 光电"寻的"竞技车
- 竞技重点: 大视场目标快速捕获及定位的能力。
- 竞赛说明:

设计一辆光电"寻的"竞技车,要求能够从指定位置出发,快速搜寻场地周边的随机点亮的信号灯。信标灯(LED灯)亮灯顺序随机,且每个灯被灭后不再亮起。比赛过程中,两参赛队同时发车,竞争到达点亮的信标灯前,当某车抵达点亮的信号灯前后,信号灯随即熄灭。在此过程中,允许己方参赛车自主干扰对方的参赛车去争夺信标灯,为自己的赛车赢得更多的机会。



课程思考

- 光电子学包含的范围?
- 激光器对人类发展的贡献?
- 如何能够做到将激光的波长覆盖全光谱?
- 光电探测器的主要实现光一电的转换,如何实现光一光的转换与控制
- 除光电转换外,人类对光的控制与利用还有其他的形式吗? 效果如何?